

## LMP8272

# High Common Mode, Gain of 14, Precision Voltage Difference Amplifier

### General Description

The LMP8272 is a fixed gain differential amplifier with a  $-2\text{V}$  to  $27\text{V}$  input common mode voltage range and a supply voltage range of  $4.75\text{V}$  to  $5.5\text{V}$ . The LMP8272 is part of the LMP™ precision amplifier family which will detect, amplify, and filter small differential signals in the presence of high common mode voltages. The gain is fixed at 14 and is adequate to drive an ADC to full scale in most cases. This fixed gain is achieved in two separate stages, a pre-amplifier with gain of +7 and a second stage amplifier with a gain of +2. The internal signal path between these two stages is brought out on two pins that provide a connection for a filter network.

The LMP8272 will operate with reduced specifications over the extended common mode input voltage range of  $-2$  to  $36$  Volts. This feature makes the device suitable for applications with load dump in automotive systems.

### Features

Typical Values,  $T_A = 25^\circ\text{C}$

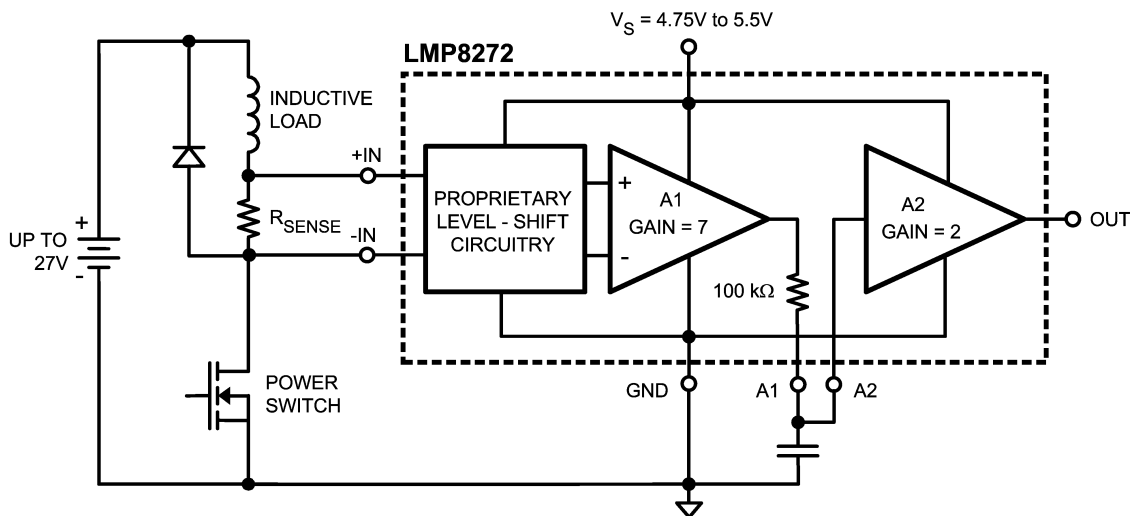
- Input Offset Voltage  $\pm 1\text{ mV max}$
- TCVo's  $\pm 15\text{ }\mu\text{V}/^\circ\text{C max}$
- CMRR  $80\text{ dB Min}$
- Extended CMVR  $-2\text{V to } 36\text{V}$
- Output Voltage Swing Rail-to-Rail
- Bandwidth  $80\text{ kHz}$
- Operating Temperature Range (Ambient)  $-40^\circ\text{C to } 125^\circ\text{C}$
- Supply Voltage  $4.75\text{V to } 5.5\text{V}$
- Supply Current  $1\text{ mA}$

### Applications

- Fuel Injection Control
- High and Low Side Driver Configuration Current Sensing
- Power Management Systems

### Typical Application

Typical Application: Low side Current Sensing



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**Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

ESD Tolerance (Note 2)

Human Body Model

For input pins only

±4000V

For All other pins

±2000V

Machine Model

200V

Supply Voltage ( $V_S$  - GND)

5.75V

Voltage on +IN and -IN

-5 to 42 Volts

Transient (400 ms)

-7 to 45 Volts

Storage Temperature Range

-65°C to +150°C

Junction Temperature (Note 3)

+150°C max

Soldering Information

Infrared or Convection (20 sec)

235°C

Wave Soldering Lead Temp. (10 sec)

260°C

**Operating Ratings** (Note 1)

Temperature Range

Packaged Devices (Note 3)

-40°C to +125°C

Supply Voltage ( $V_S$  - GND)

4.75V to 5.5V

Package Thermal Resistance ( $\theta_{JA}$  (Note 3))

8-Pin SOIC

190°C/W

**5V Electrical Characteristics** (Note 4)

Unless otherwise specified, all limits guaranteed for  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ , GND = 0,  $-2\text{V} \leq V_{CM} \leq 27\text{V}$ ,  $R_L = \text{OPEN}$ . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions		Min	Typ (Note 5)	Max	Units
$V_{OS}$	Input Offset Voltage	$V_{CM} = V_S/2$ (Note 6)			±0.25	±1.0	mV
TC $V_{OS}$	Input Offset Voltage Drift	$V_{CM} = V_S/2$	$25^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		±6	<b>±15</b>	$\mu\text{V}/^\circ\text{C}$
			$-40^\circ\text{C} \leq T_A \leq 25^\circ\text{C}$		±6	<b>±20</b>	
A2 $I_B$	Input Bias Current of A2	(Note 7)				<b>±20</b>	nA
$I_S$	Supply Current				1.0	1.2 <b>1.4</b>	mA
$R_{CM}$	Input impedance Common Mode			<b>160</b>	200	<b>240</b>	k $\Omega$
$R_{DM}$	Input impedance Differential Mode			<b>320</b>	400	<b>480</b>	k $\Omega$
CMVR	Input Common-Mode Voltage Range	Continuous		<b>-2</b>		<b>+27</b>	V
ECMVR	Extended Common-Mode Voltage Range			-2		36	V
DC CMRR	DC Common Mode Rejection Ratio	$0^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$	$-2\text{V} \leq V_{CM} \leq 27\text{V}$	<b>80</b>	97		dB
			$-2\text{V} \leq V_{CM} \leq 36\text{V}$	<b>60</b>			
		$-40^\circ\text{C} \leq T_A \leq 0^\circ\text{C}$	$-2\text{V} \leq V_{CM} \leq 27\text{V}$ $-2\text{V} \leq V_{CM} \leq 36\text{V}$	<b>77</b> <b>60</b>			
AC CMRR	AC Common Mode Rejection Ratio (Note 8)	$-2\text{V} \leq V_{CM} \leq 27\text{V}$	f = 1 kHz	80	95		dB
			f = 10 kHz		78		
PSRR	Power Supply Rejection Ratio	$4.75\text{V} \leq V_S \leq 5.5\text{V}$		<b>70</b>	80		dB
$R_{F-INT}$	Filter Resistor			<b>97</b>	100	<b>103</b>	k $\Omega$
TCR <sub>F-INT</sub>	Filter Resistor Drift				20		ppm/ $^\circ\text{C}$
$A_V$	Total Gain			13.86	14	14.14	V/V
	Gain Drift				±2	<b>±25</b>	ppm/ $^\circ\text{C}$
$A_{V1}$	A1 Gain			6.93	7	7.07	V/V
$A_{V2}$	A2 Gain			1.98	2	2.02	V/V
A1 $V_{OUT}$	A1 Output Voltage Swing		VOL		0.004	0.01	V
			VOH	4.80	4.95		
A2 $V_{OUT}$	A2 Output Voltage Swing (Notes 9, 10)	$R_L = 100\text{ k}\Omega$ on Output	VOL		0.007	0.02	V
			VOH	4.80	4.99		
		$R_L = 10\text{ k}\Omega$ on Output	VOL		0.003		V
			VOH		4.95		
SR	Slew Rate (Note 11)				0.7		V/ $\mu\text{s}$

## 5V Electrical Characteristics (Note 4) (Continued)

Unless otherwise specified, all limits guaranteed for  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $\text{GND} = 0$ ,  $-2\text{V} \leq V_{\text{CM}} \leq 27\text{V}$ ,  $R_L = \text{OPEN}$ . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min	Typ (Note 5)	Max	Units
BW	Bandwidth			80		kHz
Noise	0.1 Hz to 10 Hz			3.82		$\mu\text{Vpp}$
	Spectral Density	$f = 1 \text{ kHz}$		486		$\text{nV}/\sqrt{\text{Hz}}$

**Note 1:** Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics Tables.

**Note 2:** Human Body Model,  $1.5 \text{ k}\Omega$  in series with  $100 \text{ pF}$ . Machine Model:  $0\Omega$  in series with  $200 \text{ pF}$ .

**Note 3:** The maximum power dissipation is a function of  $T_{\text{J(MAX)}}$ ,  $\theta_{\text{JA}}$ , and  $T_A$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{\text{J(MAX)}} - T_A) / \theta_{\text{JA}}$ . All numbers apply for packages soldered directly onto a PC board.

**Note 4:** Electrical table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device.

**Note 5:** Typical values represent the parametric norm at the time of characterization.

**Note 6:** The  $V_{\text{OS}}$  maximum limit indicated does not include effect of lifetime drift, see Application Note.

**Note 7:** Positive current corresponds to current flowing into the device.

**Note 8:** AC Common Mode Signal is a  $24\text{V}_{\text{PP}}$  sine-wave ( $0\text{V}$  to  $24\text{V}$ ) at the given frequency.

**Note 9:** For VOL,  $R_L$  is connected to  $V_S$  and for VOH,  $R_L$  is connected to GND.

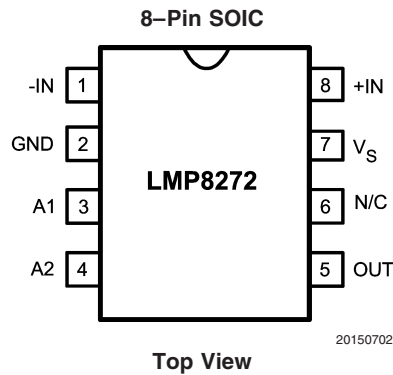
**Note 10:** For this test input is driven from A1 stage.

**Note 11:** Slew rate is the average of the rising and falling slew rates.

## Ordering Information

Package	Part Number	Package Marking	Transport Media	NSC Drawing
SOIC-8	LMP8272MA	LMP8272MA	95 Units/Rail	M08A
	LMP8271MAX		2.5K Units Tape and Reel	

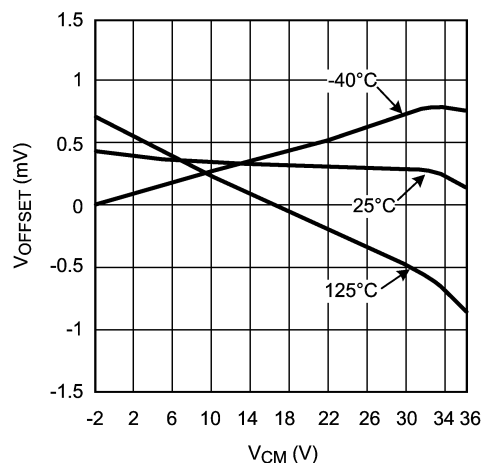
## Connection Diagram



# Typical Performance Characteristics

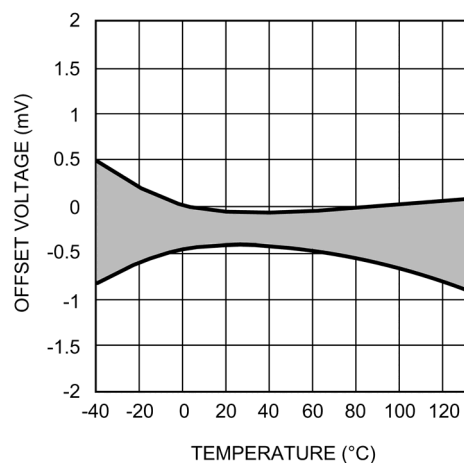
Unless otherwise specified:  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $V_{CM} = V_S/2$

## $V_{OS}$ vs. $V_{CM}$ Over Temperature



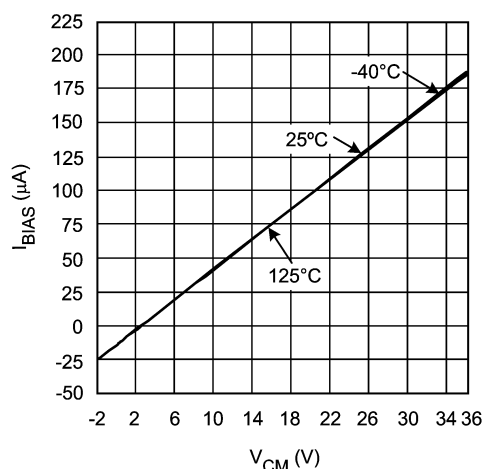
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## Typical $V_{OS}$ vs. Temperature



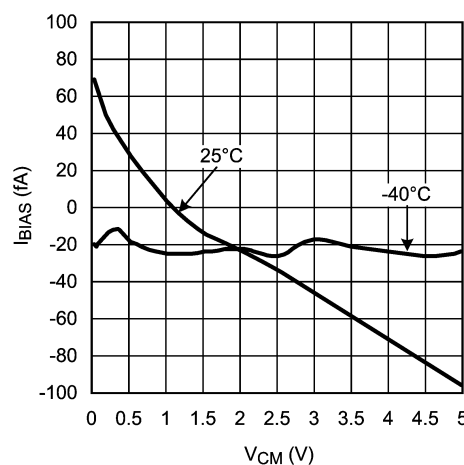
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## Input Bias Current Over Temperature (A1 Inputs)



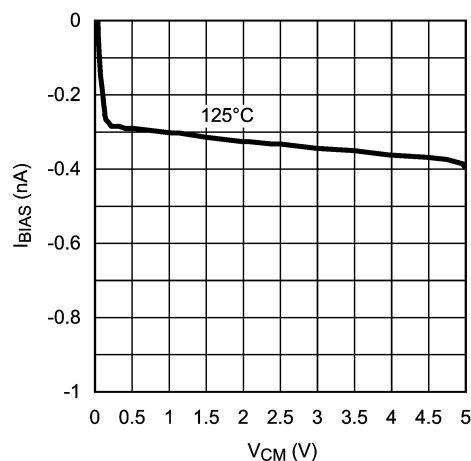
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## Input Bias Current Over Temperature (A2 Inputs)



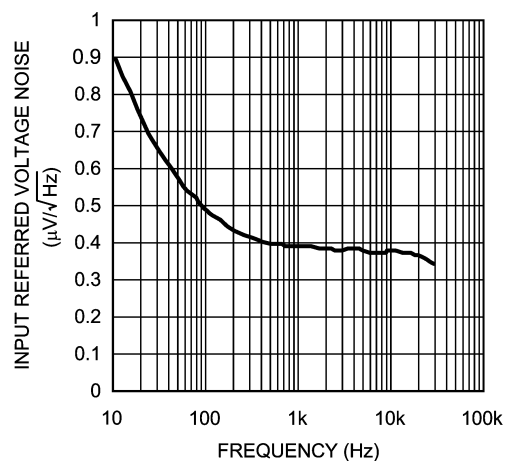
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## Input Bias Current Over Temperature (A2 Inputs)



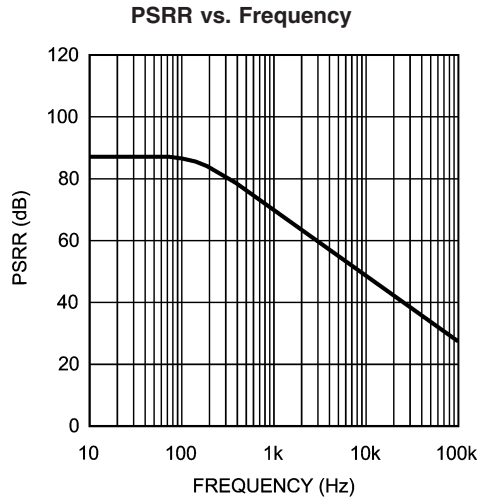
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## Input Referred Voltage Noise vs. Frequency

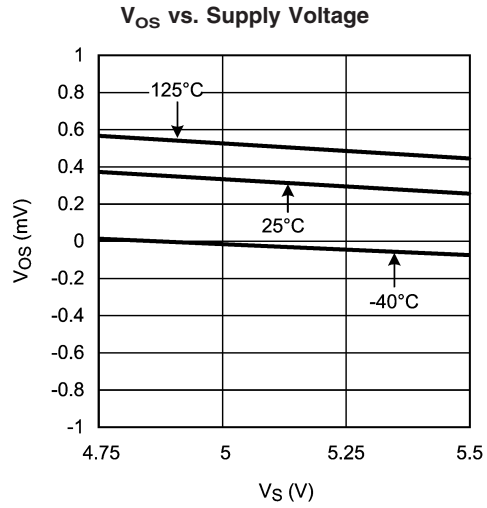


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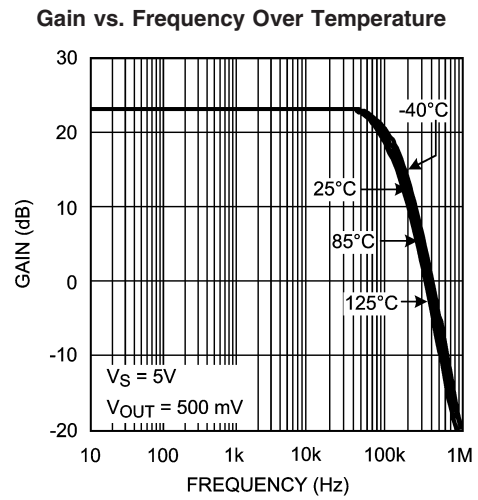
# **Typical Performance Characteristics** Unless otherwise specified: $T_A = 25^\circ\text{C}$ , $V_S = 5\text{V}$ , $V_{CM} = V_S/2$ (Continued)



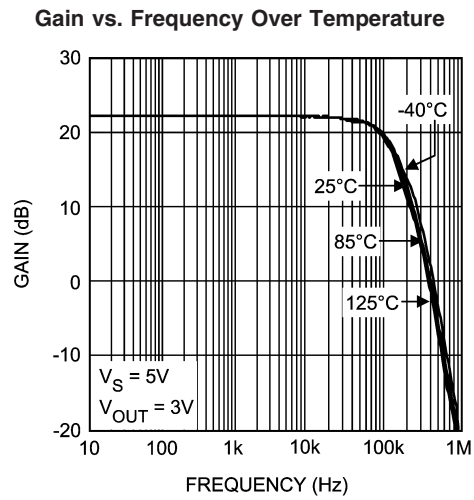
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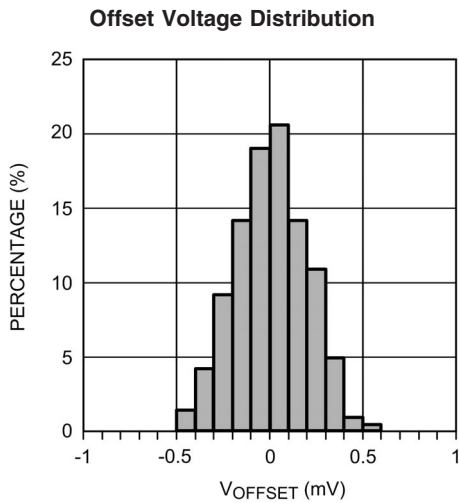
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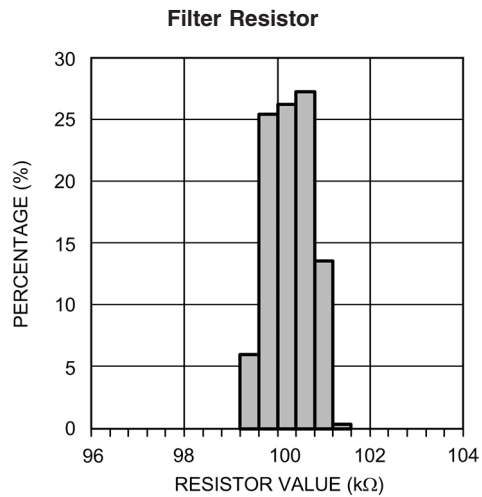
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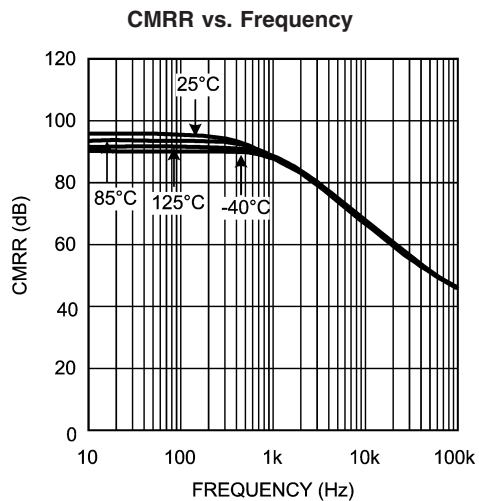
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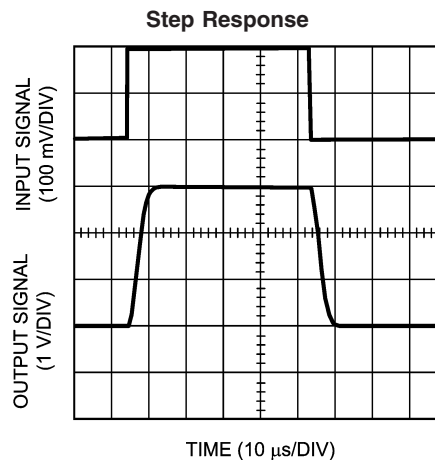
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# Typical Performance Characteristics

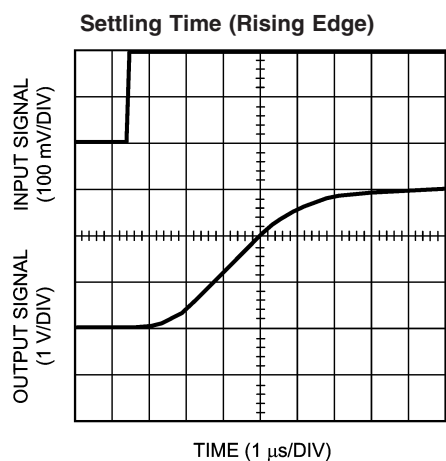
Unless otherwise specified:  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $V_{CM} = V_S/2$   
(Continued)



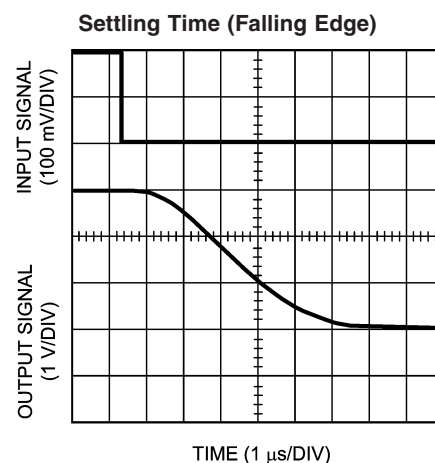
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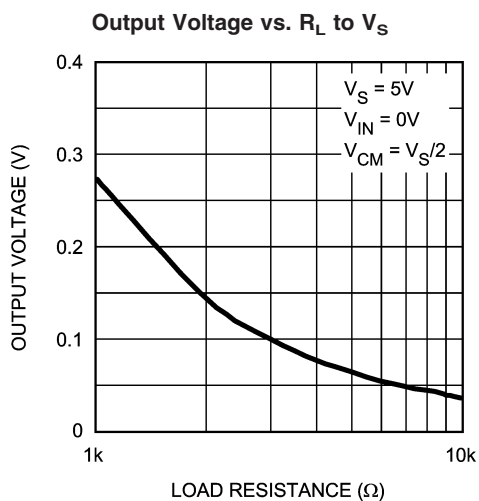
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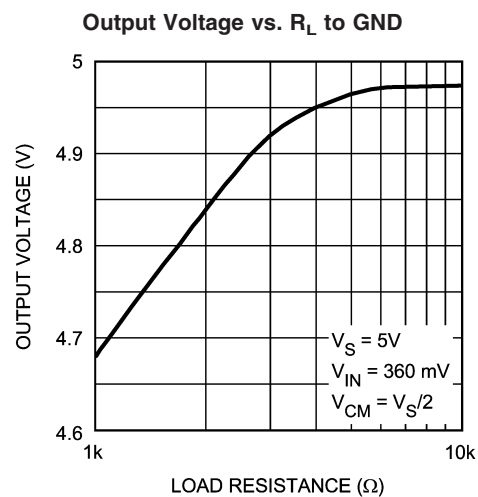
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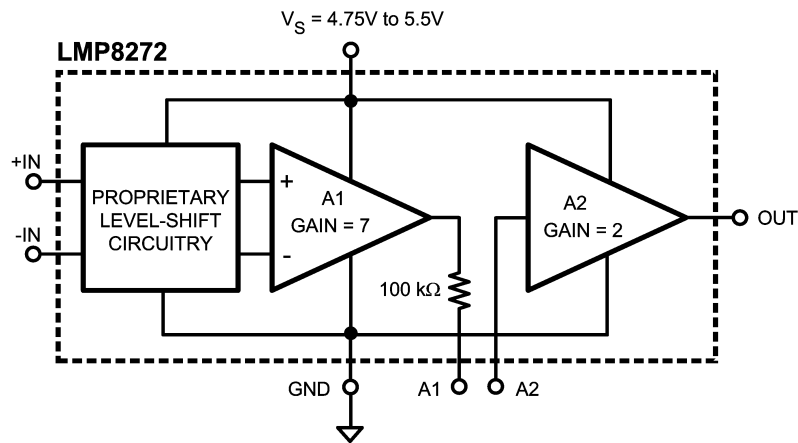


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## Application Note

### LMP8272

The LMP8272 is a single supply amplifier with a fixed gain of 14 and an extended common mode voltage range of  $-2V$  to  $36V$ . The fixed gain is achieved in two separate stages, a preamplifier with gain of  $+7$  and a second stage amplifier with gain of  $+2$ . A block diagram of the LMP8272 is shown in Figure 1.



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FIGURE 1.

The overall offset of the LMP8272 is minimized by trimming amplifier A1. This is done so that the output referred offset of A1 cancels the input referred offset of A2 or  $7V_{OS1} = -V_{OS2}$ .

Because of this offset voltage relationship, the offset of each individual amplifier stage may be more than the limit specified for the overall system in the datasheet tables. Care must be given when pin 3 and 4, A1 and A2, are connected to each other. If the signal going from A1 to A2 is amplified or attenuated (by use of amplifiers and resistors), the overall LMP8272 offset will be affected as a result. Filtering the signal between A1 and A2 or simply connecting the two pins will not change the offset of the LMP8272.

Referencing the input referred offset voltages of each stage, the following relationship holds:

$$\frac{(7V_{OS1}) + (V_{OS2})}{7} = V_{OS} (\text{LMP8272})$$

If the signal on pin 3 is scaled, attenuated or amplified, by a factor  $X$ , then the offset of the overall system will become:

$$\frac{(7V_{OS1}) \times (X) + (V_{OS2})}{7 (X)} = V_{OS} (\text{LMP8272})$$

### LIFETIME DRIFT

Input Offset Voltage is an electrical parameter which may drift over time. This drift, known as life time drift, is very common in operational amplifiers; however, its effect is more evident in precision amplifiers. This is due to the very low Input Offset Voltage specifications in these amplifiers.

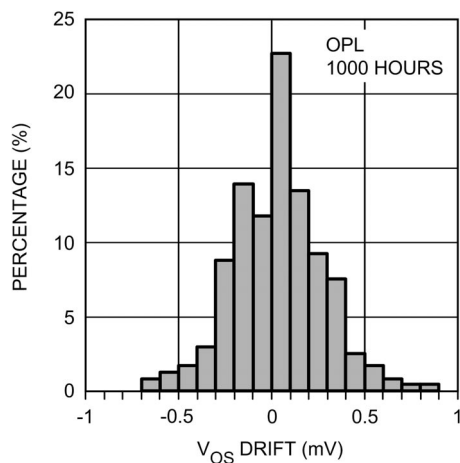
Numerous reliability tests have been performed to characterize this drift for the LMP827X family of products. Prior to each long term reliability test the Input Offset Voltage of LMP827X was measured at room temperature. The LMP827X was then subjected to a preconditioning sequence consisting of a 16 hour bake at  $125^{\circ}\text{C}$ ; an unbiased 168 hour Temperature Humidity Storage Test, THST, at  $85^{\circ}\text{C}$  and 85% humidity; four passes of infra-red reflow with a maximum temperature of  $260^{\circ}\text{C}$ ; and finally one hundred 30 min Temperature Cycles, TMCL, between  $-65^{\circ}\text{C}$  and  $150^{\circ}\text{C}$  (15 min at each temperature).

The long term reliability tests include Operating Life Time, OPL, performed at  $150^{\circ}\text{C}$  for an extended period of time; Temperature Humidity Bias Testing, THBT, at  $85^{\circ}\text{C}$  and 85% humidity for an extended period of time; and repeated cycles of TMCL.

The Offset Voltage was measured again after each reliability test at room temperature. The Offset Voltage Drift is the difference between the initial measurement, before preconditioning, and the later measurement, post preconditioning and reliability test.

Figure 2 below shows the offset voltage drift after preconditioning and 1000 hours of OPL

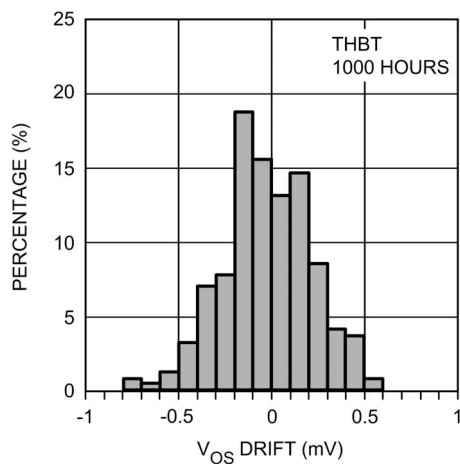
## Application Note (Continued)



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**FIGURE 2.**

Figure 3 shows the offset voltage drift after preconditioning and 1000 hours of THBT



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**FIGURE 3.**



## Application Note (Continued)

Figure 4 shows the offset voltage drift after preconditioning and a total of 1000 TMCL cycles

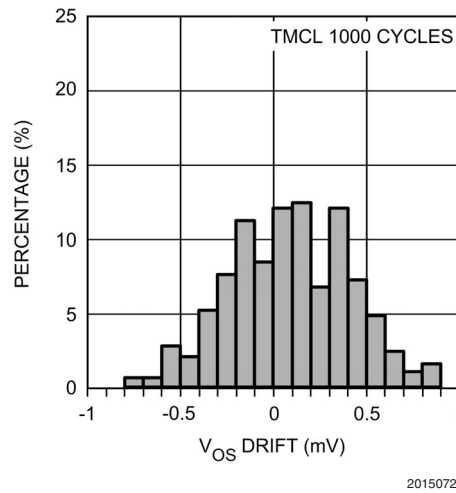


FIGURE 4.

### POWER SUPPLY DECOUPLING

In order to decouple the LMP8272 from AC noise on the power supply, it is recommended to use a 0.1  $\mu\text{F}$  on the supply pin. It is best to use a 0.1  $\mu\text{F}$  capacitor in parallel with a 10  $\mu\text{F}$  capacitor. This will generate an AC path to ground for most frequency ranges and will greatly reduce the noise introduced by the power supply.

### CURRENT LOOP RECEIVER

Many types of process control instrumentation use 4 to 20 mA transmitters to transmit the sensor's analog value to a central control room. The LMP8272 can be used as a current loop receiver as shown in Figure 5.

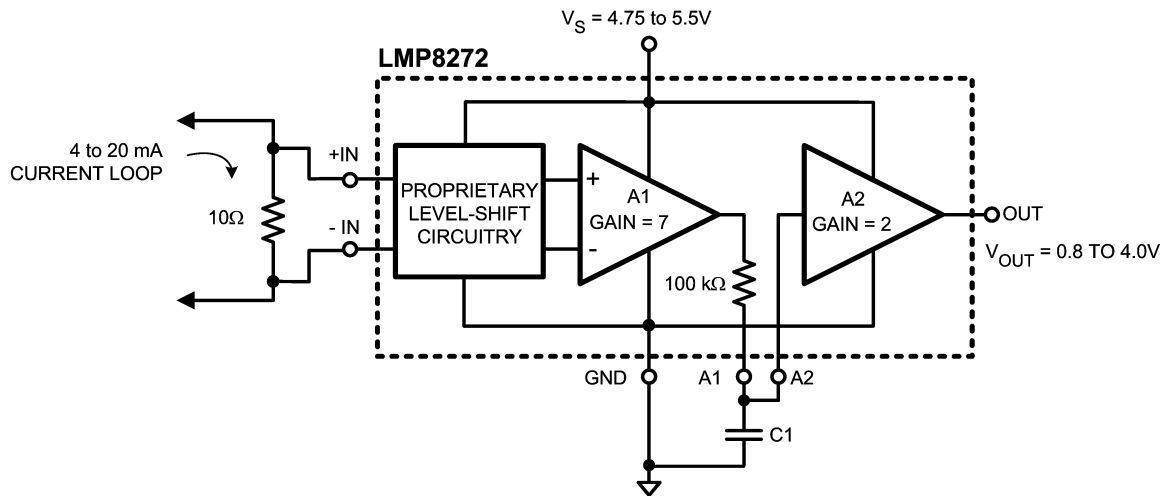


FIGURE 5.

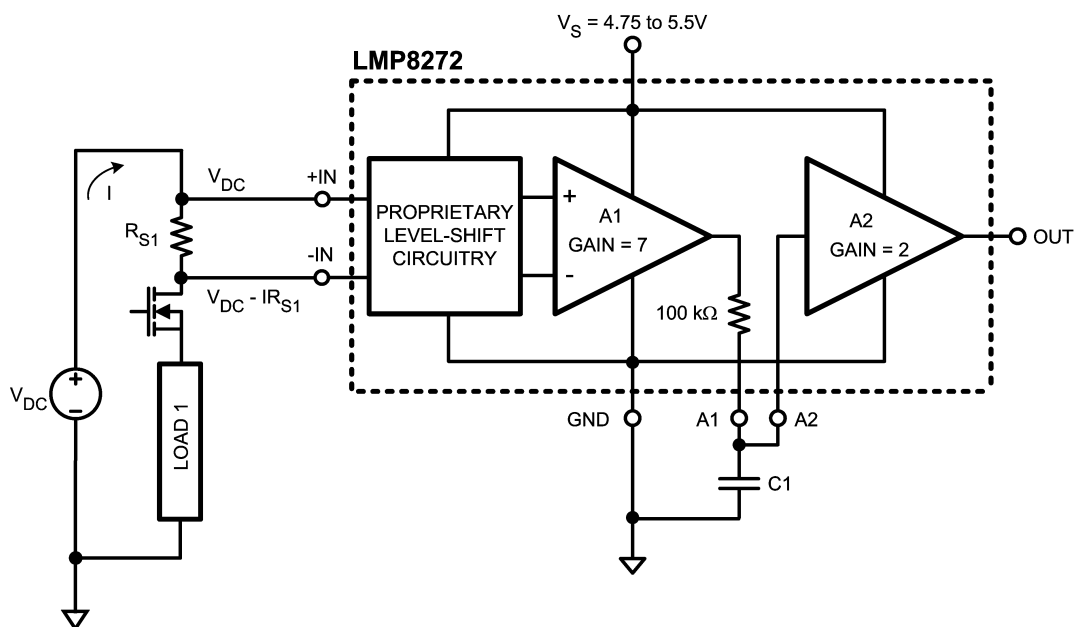
### HIGH SIDE CURRENT SENSING

High side current measurement requires a differential amplifier with gain. Here the DC voltage source represents a common mode voltage with the +IN input at the supply voltage and the -IN input very close to the supply voltage. The LMP8272 can be used with a common mode voltage,  $V_{DC}$  in this case, of up to 36 volts

The LMP8272 can be used for high side current sensing. The large common mode voltage range of this device allows it to sense signals outside of its supply voltage range. Also, the LMP8272 has very high CMRR, which enables it to sense very small signals

## Application Note (Continued)

in presence of larger common mode signals. The system in *Figure 6* couples these two characteristics of the LMP8272 in an automotive application. The signal through  $R_{S1}$  is detected and amplified by LMP8272 in the presence of a common mode signal of up to 27 Volts with highest accuracy.



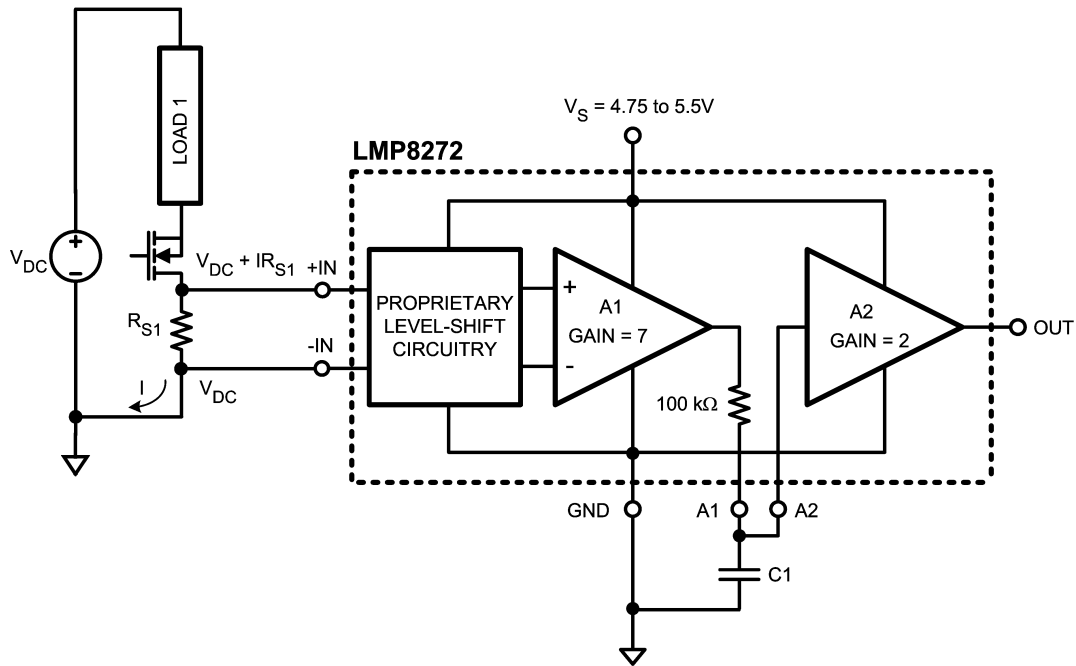
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FIGURE 6.

### LOW SIDE CURRENT SENSING

Low side current measurements can cause a problem for operational amplifiers by exceeding the negative common mode voltage limit of the device. In *Figure 7*, the load current is returning to the power source through a common connection that has a parasitic resistance. The voltage drop across the parasitic resistances can cause the ground connection of the measurement circuits to be at a positive voltage with respect to the common side of the sense resistor. This will result in one or both of the inputs being negative with respect to the circuit's ground. The LMP8272 has a wide extended input common mode voltage range of  $-2$  to  $36$  volts and will function in this condition.

## Application Note (Continued)

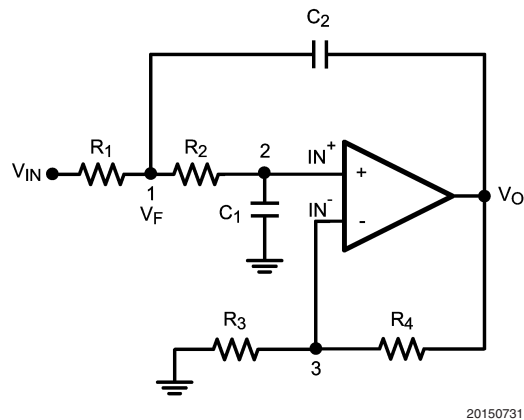


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FIGURE 7.

### SECOND ORDER LOW-PASS FILTER

The LMP8272 can be effectively used to build a second order Sallen-Key low pass filter. The general filter is shown in *Figure 8*



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FIGURE 8.

With the general transfer function:

$$\frac{V_O}{V_{IN}} = \frac{K}{M - KN}$$

(1)

Where:

$$M = s^2 C_1 C_2 R_1 R_2 + s(R_1 C_1 + R_1 C_2 + C_1 R_2) + 1$$

$$N = s C_2 R_1$$

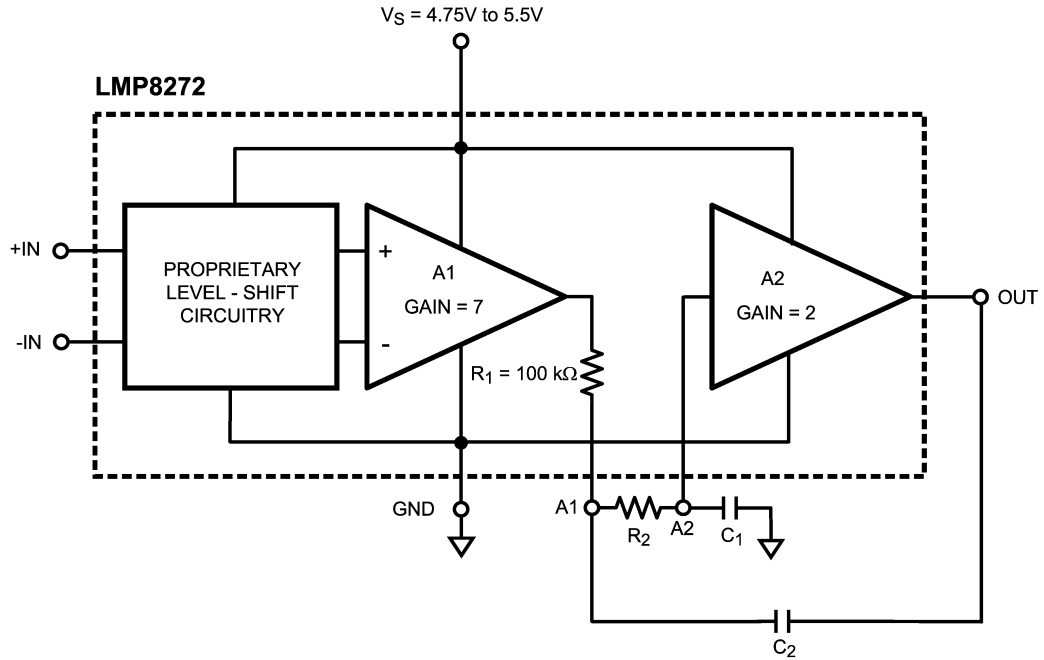
## Application Note (Continued)

and

$$\frac{1}{K} = \frac{1}{A_{VOL}} + \frac{R_3}{R_3 + R_4}$$

K represents the sum of DC closed loop gain and the non-ideality behavior of the operational amplifier. Assuming ideal behavior, the equation for K reduces simply to DC gain, which is set to +2 for the LMP8272

The LMP8272 can be used to realize this configuration as shown in *Figure 9*:



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**FIGURE 9.**

Using *Equation (1)*, the filter parameters can be calculated as follows:

$$\omega_o = \frac{1}{\sqrt{R_1 R_2 C_1 C_2}}$$

$$f_c = \frac{1}{2\pi \sqrt{R_1 R_2 C_1 C_2}}$$

$$Q = \frac{\sqrt{R_1 R_2 C_1 C_2}}{R_1 C_1 + R_2 C_1 + (1-K) R_1 C_2}$$

for the LMP8270,  $R_1 = 100\text{k}\Omega$ . Setting  $R_1 = R_2$  and  $C_1 = C_2$  results in a low-pass filter with  $Q = 1$ . Since values of resistors are predetermined, the corner frequency of this implementation of the filter depends on the capacitor values.

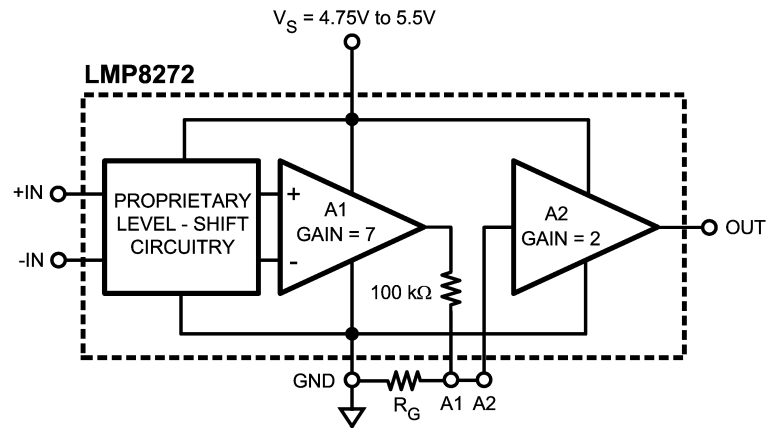
### GAINS OTHER THAN 14

The LMP8272 has an internal gain of +14; however, this gain can be modified. The signal path between the two amplifiers is available as external pins.

## Application Note (Continued)

### GAINS LESS THAN 14

Figure 10 shows the configuration used to reduce the LMP8272 gain.



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FIGURE 10.

Where:

$$\text{GAIN (NEW)} = \frac{14 R_G}{R_G + 100 \text{ k}\Omega}$$

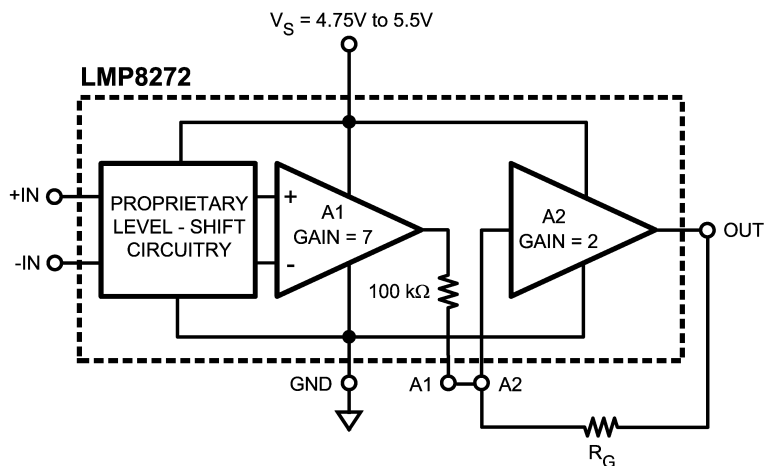
and

$$R_G = (100 \text{ k}\Omega) \frac{\text{GAIN (NEW)}}{14 - \text{GAIN (NEW)}}$$

## Application Note (Continued)

### GAINS GREATER THAN 14

A higher gain can be achieved by using positive feedback on the second stage amplifier, A2, of LMP8272. *Figure 11* shows the configuration.



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FIGURE 11.

The total gain is given by:

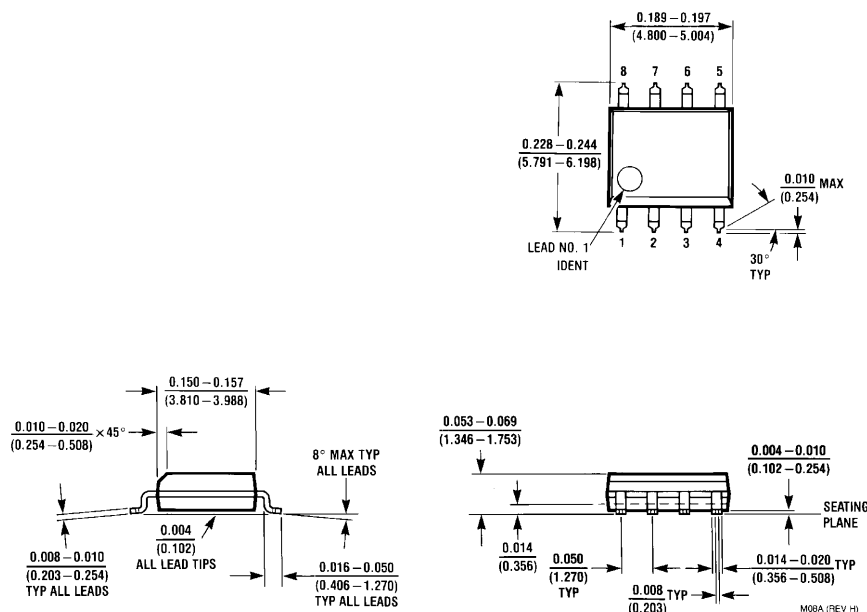
$$\text{GAIN (NEW)} = \frac{14 R_G}{R_G - 100 \text{ k}\Omega}$$

Which can be rearranged to calculate  $R_G$ :

$$R_G = (100 \text{ k}\Omega) \frac{\text{GAIN (NEW)}}{\text{GAIN (NEW)} - 14}$$

The inverting gain of the second amplifier is set at 2, giving a total system gain of 14. The non-inverting gain which is achieved through positive feedback can be less than or equal to this gain without any issues. This implies a total system gain of 28 or less is easily achievable. Once the positive gain surpasses the negative gain, the system might oscillate.

# Physical Dimensions inches (millimeters) unless otherwise noted



8-Pin SOIC  
NSC Package Number M08A

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## LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## BANNED SUBSTANCE COMPLIANCE

National Semiconductor manufactures products and uses packing materials that meet the provisions of the Customer Products Stewardship Specification (CSP-9-111C2) and the Banned Substances and Materials of Interest Specification (CSP-9-111S2) and contain no "Banned Substances" as defined in CSP-9-111S2.

Leadfree products are RoHS compliant.



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